
SYNTHESIS AND PROPERTIES
OF INORGANIC COMPOUNDS

Chemical and Phase Transformations during the Synthesis of Cs[MgR_{0.5}P_{1.5}O₆] (R = B, Al, Fe) Complex Oxides from Metal Nitrates

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Abstract—Cesium-containing complex oxides Cs[MgR_{0.5}P_{1.5}O₆], where R = B, Al, or Fe, were prepared from solutions containing H₃BO₃, metal nitrates, and H₃PO₄/NH₄H₂PO₄. The chemical and phase transformations occurring during the synthesis of these oxides were elucidated by differential thermal analysis (DTA) and X-ray powder diffraction (XRD). Optimal synthesis parameters were found. The boron compound was found to be formed at 800°C, and the aluminum and iron compounds, at 1200°C. All compounds have the pollucite structure (cubic system, space group *I4*32). A comparative analysis of the synthesis of complex oxides under study from various precursors that differed from one another in metal and phosphorus chemical species was carried out.

Keywords: metal nitrates, synthesis, complex oxide, pollucite, differential thermal analysis, X-ray powder diffraction, phase and chemical transformations

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Structural analogues of natural minerals attract the attention of researchers involved in materials design for the consolidation of hazardous components of nuclear waste [1–4]. Materials having the pollucite or pyrochlore structure are of interest for the immobilization of cesium radionuclides from radioactive waste and the creation of high specific activity γ -sources [5, 6]. An important stage in the design of such materials is studies into the processes involved in synthesis, namely, the degradation of the starting compounds and the formation and conversions of intermediates leading to the formation of the desired product. This should ultimately determine the optimal routes for the implementation of technologies under study. Those studies should pay a great deal of attention to the selection of precursors and their combinations.

We choose this approach to the development of optimal conditions preparing for crystalline cesium-containing complex oxides Cs[MgR_{0.5}P_{1.5}O₆], where R = B, Al, or Fe (the pollucite structural type) from metal chlorides. We have studied the formation of these compounds and the intermediates, their formation conditions and behavior (phase and chemical transformations) at various stages of the synthesis of desired phases. The precursors were mixtures of chemicals. For precursor I, metal chlorides were used (for the boron-containing oxide, H₃BO₃) and H₃PO₄;

precursor II differed from precursor I in that NH₄H₂PO₄ was used instead of H₃PO₄.

In the course of the synthesis of studied compounds from metal chlorides, CsCl exists in the systems up to rather high temperatures (600°C), so it can be transferred to the gas phase, as typical of alkali metal chlorides. The vaporized chloride fraction is insignificant and almost does not influence the stoichiometry of the compounds formed of it, but for the chloride comprising cesium radionuclides this process can give rise to an environmentally undesirable effect, namely, to the radioactive contamination of the equipment and environment.

It is expedient to replace chlorides in precursors, in particular, cesium chloride, by other chemical species. These chemical species can be thermally degradable nitrates, carbonates, and organometal compounds. Their use can help to reduce synthesis process parameters (*T* and τ) due to their comparatively low thermal decomposition temperatures.

In this study, we prepared the above-described complex oxides using metal nitrates (for the boron-containing oxide, H₃BO₃) and H₃PO₄ (precursor III); precursor IV was obtained by replacing H₃PO₄ by NH₄H₂PO₄.

Our goals in this study were to elucidate the processes underlying the synthesis of Cs[MgR_{0.5}P_{1.5}O₆] (R = B, Al, or Fe) oxides from precursors III and IV;

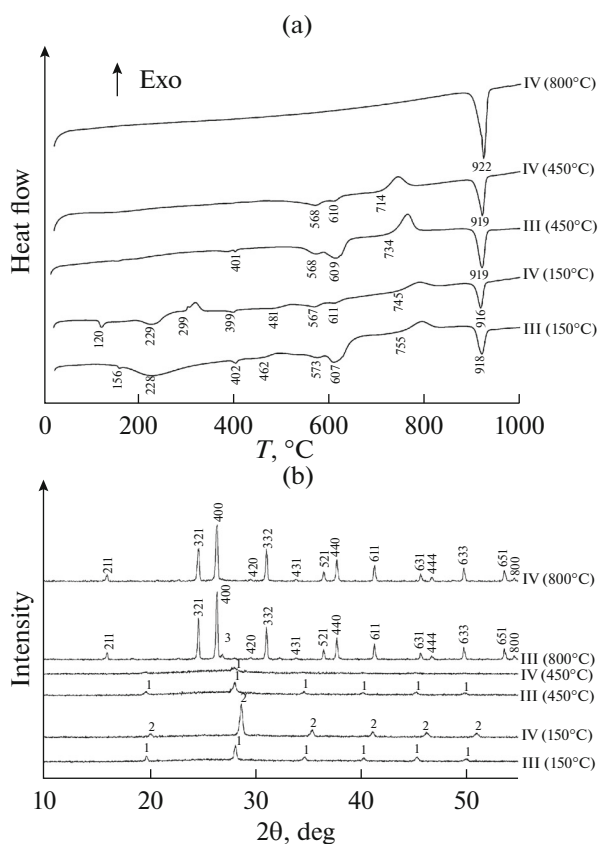


Fig. 1. (a) DTA data and (b) XRD data for precursors III and IV in the course of $\text{Cs}[\text{MgB}_{0.5}\text{P}_{1.5}\text{O}_6]$ preparation: (1) CsNO_3 (No. 01-0779), (2) CsNO_2 (No. 26-0394), (3) CsMgPO_4 (No. 45-0275), and (hkl) $\text{Cs}[\text{MgB}_{0.5}\text{P}_{1.5}\text{O}_6]$.

to determine optimal synthetic parameters, namely, temperature, the number and length of heat-treatment stages; and to perform a comparative analysis of these parameters for systems with precursors I and II (metal chloride systems).

EXPERIMENTAL

Synthesis

$\text{Cs}[\text{MgR}_{0.5}\text{P}_{1.5}\text{O}_6]$ oxides where $R = \text{B}, \text{Al},$ or Fe were prepared by sol-gel technology from two batches: batch III contained metal nitrates (for the boron-containing oxide, H_3BO_3) and H_3PO_4 ; batch IV contained $\text{NH}_4\text{H}_2\text{PO}_4$ instead of H_3PO_4 .

The chemicals used to prepare the precursor mixtures were 0.5 M H_3BO_3 solution, 1 M metal nitrate solutions, 1.5 M H_3PO_4 , or 1 M $\text{NH}_4\text{H}_2\text{PO}_4$ solution.

The as-prepared batches were heated at 80°C under stirring for 5–20 min on a magnetic stirrer; afterwards they were thermostated at 90°C until gels were formed and then at 120 – 150°C until dry residues were formed. Batch III yielded precursor III, and batch IV yielded precursor IV. The precursors were

placed into porcelain or alundum crucibles and subjected to multistage heating at temperatures from 300 to 1200°C in 100 – 150°C steps. The exposure time to each temperature was 10 – 20 h. Heat-treatment stages were alternated with 5-min dispersions with an agate mortar and a pestle.

Methods and Instruments

A sample after every heat-treatment stage was characterized by differential thermal analysis (DTA) and X-ray powder diffraction (XRD).

DTA experiments were carried out on a Setaram LABSYS differential scanning calorimeter. A polycrystalline fine-powder sample weighing ~ 100 mg was heated in a 100 - μL crucible made of high-purity Al_2O_3 at 10 K/min. The DTA experiments were carried out under an argon atmosphere. The program suite Set-Soft 2000 V 1.2 was used to process DTA curves. Thermal events were assigned with reference to relevant reference literature [7–10].

The reaction character was elucidated by the correspondence between the measured and reported values of reaction temperatures and phase-transition temperatures in the initial, intermediate, and final products.

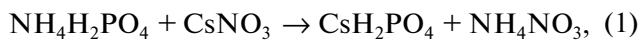
X-ray diffraction patterns were recorded on a Shimadzu LabX XRD-6000 diffractometer (filtered $\text{CuK}\alpha$ radiation, $\lambda = 1.54178 \text{ \AA}$) at 30 kV and 30 mA over the range of angles from 10° to 55° 2θ at 4 deg/min. The patterns were indexed with reference to JCPDS-ICDD PDF-2 Release 2004.

RESULTS AND DISCUSSION

DTA and XRD data on the phase and chemical transformations experienced by the $\text{Cs}[\text{MgR}_{0.5}\text{P}_{1.5}\text{O}_6]$ systems where $R = \text{B}, \text{Al},$ or Fe in the course of synthesis from precursors III and IV are compiled in Tables 1–3; some of them are shown in Figs. 1–3 as DTA curves and X-ray diffraction patterns.

$\text{Cs}[\text{MgB}_{0.5}\text{P}_{1.5}\text{O}_6]$

The DTA and XRD studies of precursors III and IV after they were heat-treated at temperatures in the range 150 – 450°C identified in them the initial CsNO_3 (polymorphic transition at 154°C and melting at 409°C), intermediates NH_4NO_3 and CsH_2PO_4 (polymorphic transitions at 125 and 230°C , respectively), and γ - HBO_2 (melting at 236°C); the intermediates were formed by the following reactions [2]:



The exotherm at 299°C is due to NH_4NO_3 decomposition by the reaction [2]

Table 1. Phase and chemical transformations during Cs[MgB_{0.5}P_{1.5}O₆] preparation

<i>T</i> , °C*	Precursor III				Precursor IV					
	DTA data			XRD data	DTA data			XRD data		
	<i>T</i> , °C		thermal feature		<i>T</i> , °C		thermal feature			
	observed	reported		observed	reported					
150	156	154	CsNO ₃ , cII → cI	CsNO ₃	120	125.5	NH ₄ NO ₃ , cII → cI	CsNO ₂		
	228	230	CsH ₂ PO ₄ , cII → cI		229	230	CsH ₂ PO ₄ , cII → cI			
		236	γ-HBO ₂ , c → l		236	γ-HBO ₂ , c → l				
	402	398	CsNO ₂ , c → l		299	>270	*Reaction (3)			
		409	CsNO ₃ , cI → l		306	302	Cs ₃ PO ₄ , cIII → cII			
	573	570	Cs ₂ O · 5B ₂ O ₃ , cIII → cII		399	398	CsNO ₂ , c → l			
			P ₄ O ₁₀ , cII → g		409	CsNO ₃ , cI → l				
	481	495	Cs ₂ O, c → l		567	570	Cs ₂ O · 5B ₂ O ₃ , cIII → cII			
	607	596	Cs ₂ O · 9B ₂ O ₃ , c → l		571	P ₄ O ₁₀ , cII → g				
	710	–	Synthesis reaction**		611	596	Cs ₂ O · 9B ₂ O ₃ , c → l			
918	–	Desired product, c → l	745	–	Synthesis reaction**					
300	157	154	CsNO ₃ , cII → cI	CsNO ₃	155	154	CsNO ₃ , cII → cI	CsNO ₃		
	400	398	CsNO ₂ , c → l		398	398	CsNO ₂ , c → l			
		409	CsNO ₃ , cI → l		409	CsNO ₃ , cI → l				
	572	570	Cs ₂ O · 5B ₂ O ₃ , cIII → cII		490	495	Cs ₂ O, c → l			
		571	P ₄ O ₁₀ , cII → g		570	570	Cs ₂ O · 5B ₂ O ₃ , cIII → cII			
	610	596	Cs ₂ O · 9B ₂ O ₃ , c → l		571	P ₄ O ₁₀ , cII → g				
	715	–	Synthesis reaction**		610	596	Cs ₂ O · 9B ₂ O ₃ , c → l			
920	–	Desired product, c → l	720	–	Synthesis reaction**					
450	156	154	CsNO ₃ , cII → cI	CsNO ₃	154	154	CsNO ₃ , cII → cI	CsNO ₃ (on the background of an amorphous phase)		
	202	206	Cs ₃ PO ₄ , cIV → cIII		568	570	Cs ₂ O · 5B ₂ O ₃ , cIII → cII			
	401	398	CsNO ₂ , c → l			571	P ₄ O ₁₀ , cII → g			
		409	CsNO ₃ , c → l		610	596	Cs ₂ O · 9B ₂ O ₃ , c → l			
	568	570	Cs ₂ O · 5B ₂ O ₃ , cIII → cII		714	–	Synthesis reaction**			
		571	P ₄ O ₁₀ , cII → g		919	–	Desired product, c → l			
	609	596	Cs ₂ O · 9B ₂ O ₃ , c → l		Desired product, CsMgPO ₄	559	570		Cs ₂ O · 5B ₂ O ₃ , cIII → cII	CsMgPO ₄
	690	–	Synthesis reaction**			669	–		Synthesis reaction**	
919	–	Desired product, c → l	919	–		Desired product, c → l				
800	914	–	Desired product, c → l	Desired product, CsMgPO ₄	922	–	Desired product, c → l	Desired product		

* The temperature of precursor heat-treatment steps; “c” denotes a crystalline phase, “l” denotes a liquid phase, “g” denotes a gas phase, and “cI – cVI” denote polymorphs of the crystalline phase;

** An exothermic reaction.

Table 2. Phase and chemical transformations during Cs[MgAl_{0.5}P_{1.5}O₆] preparation

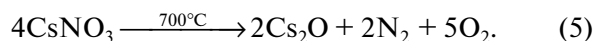
<i>T</i> , °C*	Precursor III				Precursor IV			
	DTA data			XRD data	DTA data			XRD data
	<i>T</i> , °C		thermal feature		<i>T</i> , °C		thermal feature	
	observed	reported		observed	reported			
150	156	154	CsNO ₃ , cII → cI	CsNO ₃ , AlPO ₄	122	126	NH ₄ NO ₃ , cII → cI	CsNO ₂ , AlPO ₄
	220	230	CsH ₂ PO ₄ , cII → cI		173	170	NH ₄ NO ₃ , cI → l	
	399	406	CsNO ₂ , c → l		235	200–270	Reaction** (8)	
	436	426	Mg(NO ₃) ₂ , c → l		303	>270	Reaction** (3)	
	528	518	Cs ₅ P ₃ O ₁₀ , c → l + cI		397	398	CsNO ₂ , c → l	
	665	672	Cs, l → g		419	426	Mg(NO ₃) ₂ , c → l	
	521	518	Cs ₅ P ₃ O ₁₀ , c → l + cI					
300	154	154	CsNO ₃ , cII → cI	CsNO ₃ , AlPO ₄	152	154	CsNO ₃ , cII → cI	CsNO ₃ , AlPO ₄
	400	406	CsNO ₂ , c → l		398	398	CsNO ₂ , c → l	
	462	465	Cs ₃ PO ₄ , cII → cI		421	426	Mg(NO ₃) ₂ , c → l	
	529	518	Cs ₅ P ₃ O ₁₀ , c → l + cI		528	518	Cs ₅ P ₃ O ₁₀ , c → l + cI	
	670	672	Cs, l → g		632	–	Unidentified	
450	152	154	CsNO ₃ , cII → cI	CsMgPO ₄ , CsNO ₃ , AlPO ₄	151	154	CsNO ₃ , cII → cI	CsMgPO ₄ , CsNO ₃ , AlPO ₄
	392	406	CsNO ₂ , c → l		196	186	Cs ₂ Mg(NO ₃) ₄ , c → l	
	563	580	AlPO ₄ , cVI → cV		389	398	CsNO ₂ , c → l	
	654	–	Unidentified		550	557	CsO ₂ , c → l	
600	Unobserved			CsMgPO ₄ , AlPO ₄	Unobserved			CsMgPO ₄ , AlPO ₄
800	Unobserved			CsMgPO ₄ , AlPO ₄	Unobserved			CsMgPO ₄ , AlPO ₄ , desired product
1000	Unobserved			CsMgPO ₄ , desired product, AlPO ₄	Unobserved			CsMgPO ₄ , desired product, AlPO ₄
1200	Unobserved			Desired product	Unobserved			Desired product

* The temperature of precursor heat-treatment steps; “c” denotes a crystalline phase, “l” denotes a liquid phase, “g” denotes a gas phase, and “cI – cVI” denote polymorphs of the crystalline phase;

** An exothermic reaction.



The initial cesium nitrate decomposes to CsNO₂ (melting at 398°C) and Cs₂O (melting at 490°C) by the reactions



The exotherm at *T* = 706°C characterizes the desired product synthesis reaction, and the endotherm at 916°C is due to its melting.

Subsequent heating to 450°C reduced the contents of CsNO₃ and its decomposition products in the systems with simultaneous detection of cesium and boron double oxides on DTA curves. XRD identified only CsNO₃.

Table 3. Phase and chemical transformations during Cs[MgFe_{0.5}P_{1.5}O₆] preparation

T, °C*	Precursor III				Precursor IV			
	DTA data			XRD data	DTA data			XRD data
	T, °C		thermal feature		T, °C		thermal feature	
	observed	reported			observed	reported		
150	230	230	CsH ₂ PO ₄ , cII → cI	CsMgPO ₄ (on the back-ground of an amorphous phase)	124	126	NH ₄ NO ₃ , cII → cI	CsNO ₂
	394	398	CsNO ₂ , cI → l		190	186	Cs ₂ Mg(NO ₃) ₄ , c → l	
	568	557	CsO ₂ , c → l		190	190	NH ₄ H ₂ PO ₄ , c → l	
		571	P ₄ O ₁₀ , cII → g		255	200–270	*Reaction (7)	
	594	594	Cs ₂ O ₂ , c → l		290	>270	*Reaction (3)	
	707	700	Cs ₂ Fe ₂ P ₂ O ₇ , cII → cI		417	409	CsNO ₃ , cI → l	
		715	Cs ₃ Fe ₂ (PO ₄) ₃ , cII → cI		547	557	CsO ₂ , c → l	
814	815	CsMg(PO ₃) ₃ , c → l	890	889	FePO ₄ , cII → cI			
300	163	154	CsNO ₃ , cII → cI	CsMgPO ₄ (on the back-ground of an amorphous phase)	154	154	CsNO ₃ , cII → cI	CsNO ₃ (on the back-ground of an amorphous phase)
	414	409	CsNO ₃ , cI → l		416	409	CsNO ₃ , cI → l	
	567	571	P ₄ O ₁₀ , cII → g		547	557	CsO ₂ , c → l	
	717	715	Cs ₃ Fe ₂ (PO ₄) ₃ , cII → cI		818	815	CsMg(PO ₃) ₃ , c → l	
	747	746	Cs ₆ Fe ₂ (P ₂ O ₇) ₃ , c → l		853	856	Cs ₂ Fe ₂ P ₂ O ₇ , cI → l	
	824	815	CsMg(PO ₃) ₃ , c → l		887	889	FePO ₄ , cII → cI	
450	577	571	P ₄ O ₁₀ , cII → g	CsMgPO ₄ (on the back-ground of an amorphous phase)	570	571	P ₄ O ₁₀ , cII → g	CsMgPO ₄ , CsNO ₃
	700	700	Cs ₂ Fe ₂ P ₂ O ₉ , cII → cI		682	–	Synthesis reaction**	
	728	715	Cs ₃ Fe ₂ (PO ₄) ₃ , cII → cI		854	856	Cs ₂ Fe ₂ P ₂ O ₇ , cI → l	
	841	842	Cs ₃ Fe ₂ (PO ₄) ₃ , cI → l		891	889	FePO ₄ , cII → cI	
	944	940	Fe(PO ₃) ₃ , cII → cI					
600	543	557	CsO ₂ , c → l	CsMgPO ₄ , desired product	687	–	Synthesis reaction**	CsMgPO ₄ , desired product
	817	815	CsMg(PO ₃) ₃ , c → l		778	784	FePO ₄ , cIII → cII	
	848	842	Cs ₃ Fe ₂ (PO ₄) ₃ , cI → l		856	856	Cs ₂ Fe ₂ P ₂ O ₇ , cI → l	
	877	865	Fe ₄ (P ₂ O ₇) ₃ , cII → cI		891	889	FePO ₄ , cII → cI	
		889	FePO ₄ , cII → cI		946	940	Fe(PO ₃) ₃ , cII → cI	
	932	940	Fe(PO ₃) ₃ , cII → cI					
800	318	302	Cs ₃ PO ₄ , cIII → cII	Desired product, CsMgPO ₄	857	856	Cs ₂ Fe ₂ P ₂ O ₇ , cI → l	Desired product, CsMgPO ₄
	857	856	Cs ₂ Fe ₂ P ₂ O ₇ , cI → l		894	889	FePO ₄ , cII → cI	
	893	889	FePO ₄ , cII → cI					
1000	Unobserved			Desired product, CsMgPO ₄	Unobserved			Desired product, CsMgPO ₄
1200					Desired product, CsMgPO ₄			

* The temperature of precursor heat-treatment steps; “c” denotes a crystalline phase, “l” denotes a liquid phase, “g” denotes a gas phase, and “cI – cVI” denote polymorphs of the crystalline phase;

** An exothermic reaction.

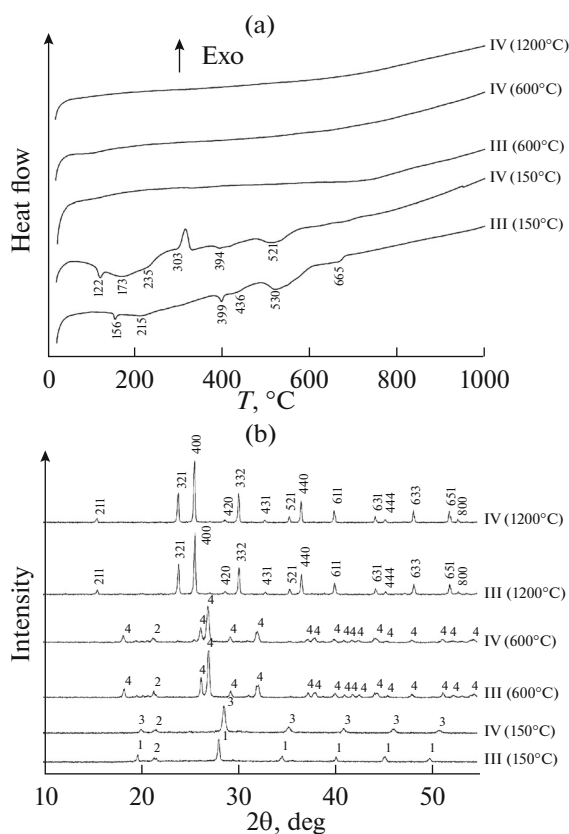


Fig. 2. (a) DTA data and (b) XRD data for precursors III and IV in the course of $\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$ preparation: (1) CsNO_3 (No. 01-0779), (2) AlPO_4 (No. 87-1127), (3) CsNO_2 (No. 26-0394), (4) CsMgPO_4 (No. 45-0275), and (hkl) $\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$.

The exothermic reaction of desired product synthesis and its melting endotherm appear on DTA curves for all thermal exposure stages in the range 150–600°C.

After precursors were exposed at 600°C, they contained, as found by DTA, the desired product and a $\text{Cs}_2\text{O} \cdot 5\text{B}_2\text{O}_3$ admixture, and as found by XRD, the desired product and CsMgPO_4 . The heat treatment of the precursors at 800°C yielded, as found by DTA and XRD, the desired product with a CsMgPO_4 minor phase.

The overall reactions for synthesis of the boron-containing desired product from precursors III and IV are given below:

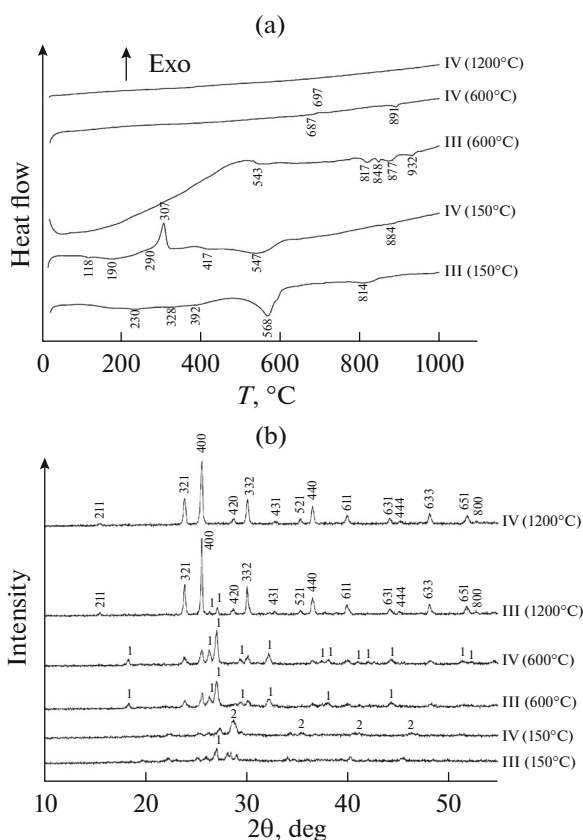
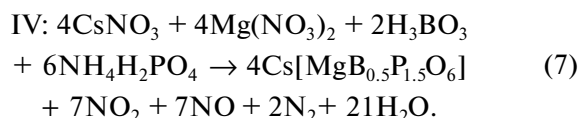
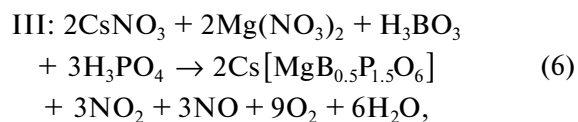
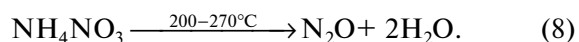


Fig. 3. (a) DTA data and (b) XRD data for precursors III and IV in the course of $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$ preparation: (1) CsMgPO_4 (No. 45-0275), (2) CsNO_2 (No. 26-0394), and (hkl) $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$.

$\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$

The DTA and XRD studies of precursors III and IV after they were heat-treated at temperatures in the range 150–450°C show the initial cesium and magnesium nitrates, thermal degradation products of cesium nitrate (cesium nitrite and cesium peroxide), and intermediates: ammonium nitrate, cesium and aluminum phosphates, and cesium magnesium double nitrate.

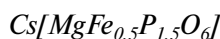
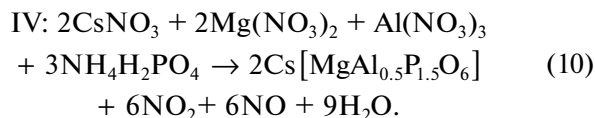
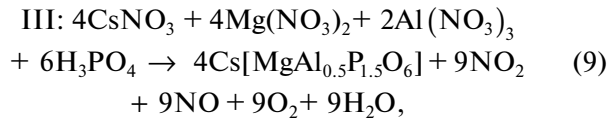
The exotherms at 235 and 300°C correspond to NH_4NO_3 decomposition by reactions (3) and (8) [2]:



After heating in the range 600–1200°C, the DTA curves of the systems are featureless.

X-ray powder diffraction patterns show that the heat treatment of the precursors at 800°C produced a two-phase system comprised of CsMgPO_4 and $\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$, the latter increasing as the exposure temperature elevated to 1100°C. An individual phase of the desired product was formed after the precursors were heat treated at 1200°C.

The overall reactions for the synthesis of $\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$ from precursors III and IV are the following:



After precursors III and IV were heat-treated at temperatures in the range 150–450°C, their DTA curves show the initial products (ammonium dihydrogenphosphate and cesium nitrate) and intermediates (cesium nitrite, cesium oxides, metal phosphates, cesium magnesium and cesium iron double phosphates). At higher temperatures, iron and magnesium phosphates are detected, as well as cesium magnesium and cesium iron double phosphates.

In the precursors heat-treated at 150 and 300°C, XRD shows that CsNO_2 and CsNO_3 phases can be distinguished on the background of an amorphous phase; after heating at 450°C, P_4O_{10} and CsMgPO_4 phases appear. Exposure of the precursors at 600°C gives rise to the formation of a two-phase system comprised of CsMgPO_4 (the major phase) and $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$ (the minor phase). As in the case of the aluminum-containing compound, the desired product fraction increases as temperature rises from 800 to 1200°C. Heat treatment at 1200°C makes it possible to prepare $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$ as an individual phase.

The intermediates formed in the course of $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$ synthesis are iron phosphates and pyrophosphates, double cesium phosphates and pyrophosphates of iron and magnesium.

A desired product phase starts to form at 600°C, as evidenced by the appearance of its reflections on the background of the major phase CsMgPO_4 . When temperature rises to 1000°C, the major phase becomes the desired product and the minor phase is CsMgPO_4 , the latter disappearing at 1200°C.

The overall reactions for the synthesis of $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$ from precursors III and IV are shown below:

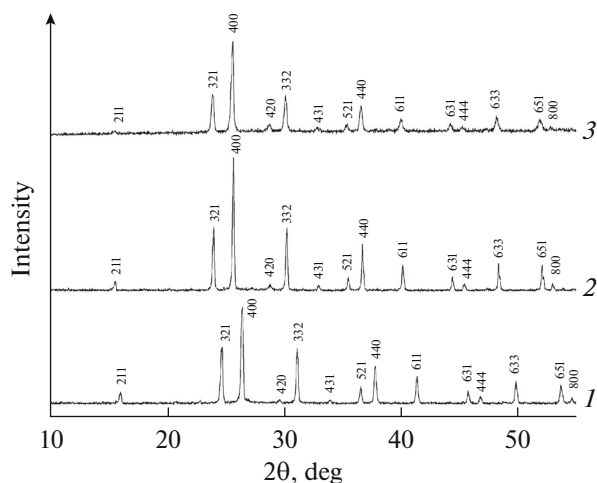
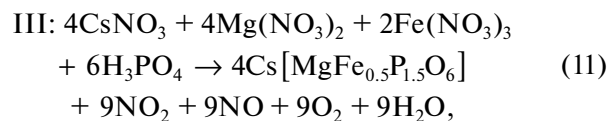
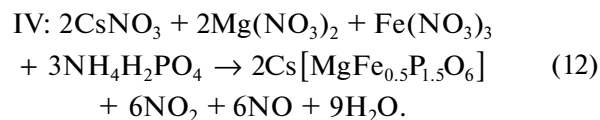


Fig. 4. XRD data: (1) $\text{Cs}[\text{MgB}_{0.5}\text{P}_{1.5}\text{O}_6]$, $T = 800^\circ\text{C}$; (2) $\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$, $T = 1200^\circ\text{C}$; and (3) $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$, $T = 1200^\circ\text{C}$. Analogue: $\text{Cs}_2\text{Co}_2\text{Al}(\text{PO}_4)_3$ [10].



Based on the data obtained, we may recommend one to include the following steps into the synthesis of $\text{Cs}[\text{MgR}_{0.5}\text{P}_{1.5}\text{O}_6]$ compounds where $\text{R} = \text{B}, \text{Al},$ or Fe : drying of the batch at 150°C; heat treatment at 600°C for 20 h; and final heat treatment for 20 h at 800°C for $\text{Cs}[\text{MgB}_{0.5}\text{P}_{1.5}\text{O}_6]$ and at 1200°C for $\text{Cs}[\text{MgAl}_{0.5}\text{P}_{1.5}\text{O}_6]$ and $\text{Cs}[\text{MgFe}_{0.5}\text{P}_{1.5}\text{O}_6]$ (Fig. 4).

All prepared compounds crystallize in the pollucite structural type, cubic crystal system, space group $I4_32$ (an analogue of $\text{Cs}_2\text{Co}_2\text{Al}(\text{PO}_4)_3$ [4]). The unit cell parameter a in the $\text{Cs}[\text{MgR}_{0.5}\text{P}_{1.5}\text{O}_6]$ ($\text{R} = \text{B}, \text{Al},$ or Fe) series is 13.433, 13.814, and 13.866 Å, respectively (the increase in unit cell parameter value correlates with the increase in the ionic radii of trivalent cations B^{3+} , Al^{3+} , and Fe^{3+}).

From a comparative analysis of the synthetic protocols for preparing cesium-containing complex oxides from various precursors that differ from one another by chemical species of the metals (chlorides or nitrates) and phosphorus (H_3PO_4 or $\text{NH}_4\text{H}_2\text{PO}_4$), it flows that the lowest synthesis temperature (800°C) is typical of all precursors (I–IV) of the boron-containing complex oxide. The iron-containing oxide is formed at 800°C from precursor I, at 1000°C from precursor II, and at 1200°C from precursor IV. The highest synthesis temperature is observed for the aluminum-containing compound: 1100°C from precursor I or precursor II and 1200°C from precursor III or IV.

CONCLUSIONS

Apart from the thermal decomposition of boric acid, phosphoric acid, and ammonium dihydrogenphosphate observed in chloride systems, $\text{Cs}[\text{MgR}_{0.5}\text{P}_{1.5}\text{O}_6]$ (R = B, Al, or Fe) synthesis from metal nitrates involves the thermal decomposition of the nitrates. The following intermediates are formed: cesium dihydrogenphosphate and cesium nitrate, ammonium nitrate, metal phosphates, cesium and phosphorus oxides, cesium and boron double oxides, and double cesium nitrates and phosphates of magnesium and iron.

The formation reactions of intermediates and the overall reactions of the synthesis of desired products have been described. The synthesis temperature of the studied complex oxides is independent of whether precursor III or IV is used, being 800°C for the oxide where R = B and 1200°C for the oxides where R = Al or Fe. The prepared compounds have the pollucite structure (cubic space group $I4_132$).

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